



# TPS62160-Q1 具有 DCS-Control™ 功能的 3V 到 17V 1A 降压转换器

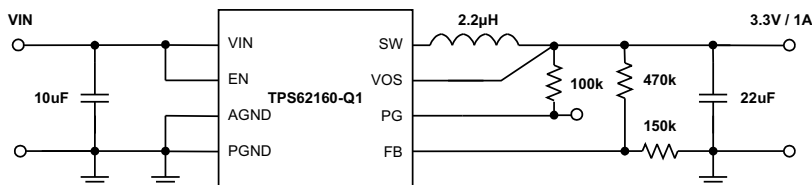
## 1 特性

- DCS-Control™ 拓扑技术
- 符合汽车应用要求
- 具有符合 AEC-Q100 的下列结果：
  - 器件温度等级：-40°C 至 125°C 的运行结温范围
  - 器件人体模型 (HBM) 静电放电 (ESD) 分类等级 H2
  - 器件充电器件模型 (CDM) ESD 分类等级 C4B
- 输入电压范围：3V 至 17V
- 输出电流高达 1A
- 可调输出电压范围为 0.9V 至 6V
- 固定输出电压版本
- 无缝省电模式转换
- 静态电流典型值为 17μA
- 电源正常输出
- 100% 占空比模式
- 短路保护
- 过热保护
- 采用 2mm x 2mm 晶圆级小外形无引线 (WSON)-8 封装

## 2 应用

- 汽车类 12V 导轨式电源
- 以太网供电 (POE) 的同轴负载点 (POL) 电源
- 摄像机模块、视频模块
- 低压降稳压器 (LDO)

## 4 简化电路原理图



## 3 说明

TPS62160-Q1 是一款易于使用的同步降压 DC-DC 转换器，针对高功率密度的应用进行了优化。该器件的开关频率典型值高达 2.25MHz，允许使用小型电感器，通过利用 DCS-Control™ 拓扑技术提供快速的瞬态响应并实现高输出电压精度。

此器件具有 3V 至 17V 宽运行输入电压范围，非常适用于由锂离子或其它电池以及 12V 中间电源轨供电的系统。其输出电压为 0.9V 至 6V，支持高达 1A 的持续输出电流（使用 100% 占空比模式）。

通过配置使能引脚和开漏电源正常状态引脚也可以实现电源排序。

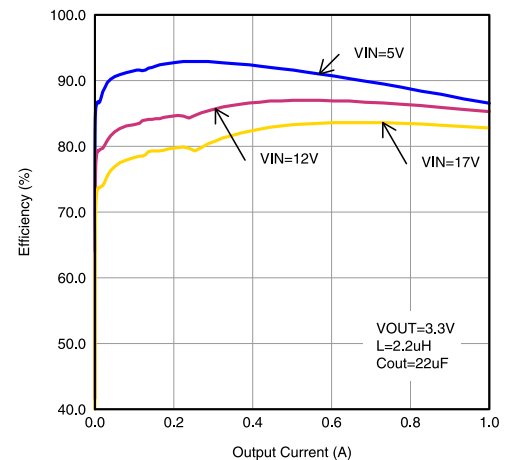
在节能模式下，器件可根据输入电压 (VIN) 生成约 17μA 的静态电流。负载较小时可自动且无缝进入节能模式，同时该模式可保持整个负载范围内的高效率。在关断模式下，此器件会关闭且关断期间的流耗少于 2μA。

此器件采用 2mm x 2mm (DSG) 8 引脚 WSON 封装。

器件信息<sup>(1)</sup>

器件型号	封装	封装尺寸 (标称值)
TPS62160-Q1	WSON (8)	2.00mm x 2.00mm

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。



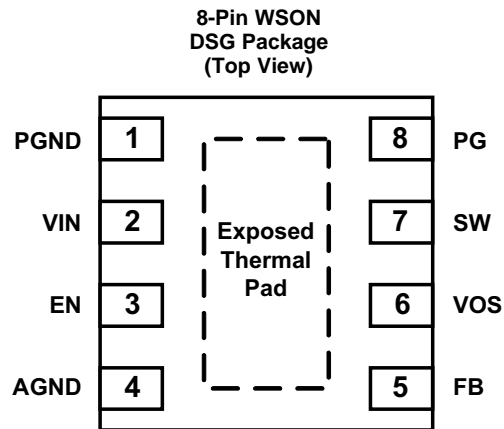
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## 5 修订历史记录

日期	修订版本	注释
2014年12月	*	最初发布。

## 6 Pin Configuration and Functions



### Pin Functions

PIN <sup>(1)</sup>		I/O	DESCRIPTION
NAME	NUMBER		
PGND	1		Power ground
VIN	2	I	Supply voltage
EN	3	I	Enable input (High = enabled, Low = disabled)
AGND	4		Analog Ground
FB	5	I	Voltage feedback of adjustable version. Connect resistive voltage divider to this pin. It is recommended to connect FB to AGND on fixed output voltage versions for improved thermal performance.
VOS	6	I	Output voltage sense pin and connection for the control loop circuitry.
SW	7	O	Switch node, which is connected to the internal MOSFET switches. Connect inductor between SW and output capacitor.
PG	8	O	Output power good (High = VOUT ready, Low = VOUT below nominal regulation) ; open drain (requires pull-up resistor; goes high impedance, when device is switched off)
Exposed Thermal Pad			Must be connected to AGND. Must be soldered to achieve appropriate power dissipation and mechanical reliability.

(1) For more information about connecting pins, see [Detailed Description](#) and [Application Information](#) sections.

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating junction temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Pin voltage range <sup>(2)</sup>	VIN	−0.3	20	V
	EN, SW	−0.3	VIN+0.3	V
	FB, PG, VOS	−0.3	7	V
Power Good sink current	PG		10	mA
Operating junction temperature range, TJ		−40	125	°C
Storage temperature range, Tstg		−65	150	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to network ground terminal.

### 7.2 ESD Ratings

			VALUE	UNIT
V(ESD)	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 <sup>(1)</sup>	±2000	V
		Charged device model (CDM), per AEC Q100-011	±500	

- (1) AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 7.3 Recommended Operating Conditions

over operating junction temperature range (unless otherwise noted)

		MIN	TYP	MAX	UNIT
VIN	Supply voltage	3		17	V
VOU	Output voltage range	0.9		6	V
TJ	Operating junction temperature	−40		125	°C

### 7.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TPS62160-Q1		UNIT
		DSG (8 PINS)	DGK (8 PINS)	
RθJA	Junction-to-ambient thermal resistance	61.8	184.3	°C/W
RθJC(top)	Junction-to-case (top) thermal resistance	61.3	74.6	
RθJB	Junction-to-board thermal resistance	15.5	105.8	
ΨJT	Junction-to-top characterization parameter	0.4	13.3	
ΨJB	Junction-to-board characterization parameter	15.4	104.2	
RθJC(bot)	Junction-to-case (bottom) thermal resistance	8.6	-	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

## 7.5 Electrical Characteristics

Over junction temperature range ( $T_J = -40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ ), typical values at  $V_{IN} = 12\text{ V}$  and  $T_J = 25^{\circ}\text{C}$  (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
V <sub>IN</sub>	Input voltage range <sup>(1)</sup>		3		17	V
I <sub>Q</sub>	Operating quiescent current	EN = High, I <sub>OUT</sub> = 0 mA, Device not switching		17	30	μA
I <sub>SD</sub>	Shutdown current <sup>(2)</sup>	EN = Low		1.8	25	μA
V <sub>UVLO</sub>	Undervoltage lockout threshold	Falling input voltage	2.6	2.7	2.82	V
		Hysteresis		180		mV
T <sub>SD</sub>	Thermal shutdown temperature			160		°C
	Thermal shutdown hysteresis			20		
CONTROL (EN, PG)						
V <sub>EN_H</sub>	High level input threshold voltage (EN)		0.9			V
V <sub>EN_L</sub>	Low level input threshold voltage (EN)				0.3	V
I <sub>LKG_EN</sub>	Input leakage current (EN)	EN = V <sub>IN</sub> or GND		0.01	1	μA
V <sub>TH_PG</sub>	Power Good threshold voltage	Rising (%V <sub>OUT</sub> )	92%	95%	98%	
		Falling (%V <sub>OUT</sub> )	87%	90%	93%	
V <sub>OL_PG</sub>	Power Good output low	I <sub>PG</sub> = −2 mA		0.07	0.3	V
I <sub>LKG_PG</sub>	Input leakage current (PG)	V <sub>PG</sub> = 1.8 V		1	400	nA
POWER SWITCH						
R <sub>DS(ON)</sub>	High-side MOSFET ON-resistance	V <sub>IN</sub> ≥ 6 V		300	600	mΩ
		V <sub>IN</sub> = 3 V		430		
	Low-side MOSFET ON-resistance	V <sub>IN</sub> ≥ 6 V		120	200	mΩ
		V <sub>IN</sub> = 3 V		165		
I <sub>LIMF</sub>	High-side MOSFET forward current limit <sup>(3)</sup>	V <sub>IN</sub> = 12 V, T <sub>A</sub> = 25°C	1.45	1.95	2.45	A
OUTPUT						
V <sub>REF</sub>	Internal reference voltage			0.8		V
I <sub>LKG_FB</sub>	Pin leakage current (FB)	V <sub>FB</sub> = 1.2 V		5	400	nA
V <sub>OUT</sub>	Output voltage range	V <sub>IN</sub> ≥ V <sub>OUT</sub>	0.9		6.0	V
	Feedback voltage accuracy	PWM Mode operation, V <sub>IN</sub> ≥ V <sub>OUT</sub> + 1 V	−3%		3%	
		Power Save Mode operation, C <sub>OUT</sub> = 2x22 μF <sup>(4)</sup>	−3%		4%	
		DC output voltage load regulation <sup>(5)</sup>	V <sub>IN</sub> = 12 V, V <sub>OUT</sub> = 3.3 V, PWM Mode operation		0.05	
	DC output voltage line regulation <sup>(5)</sup>	3 V ≤ V <sub>IN</sub> ≤ 17 V, V <sub>OUT</sub> = 3.3 V, I <sub>OUT</sub> = 0.5 A, PWM Mode operation		0.02		% / V

(1) The device is still functional down to Under Voltage Lockout (see parameter  $V_{UVLO}$ ).

(2) Current into VIN pin.

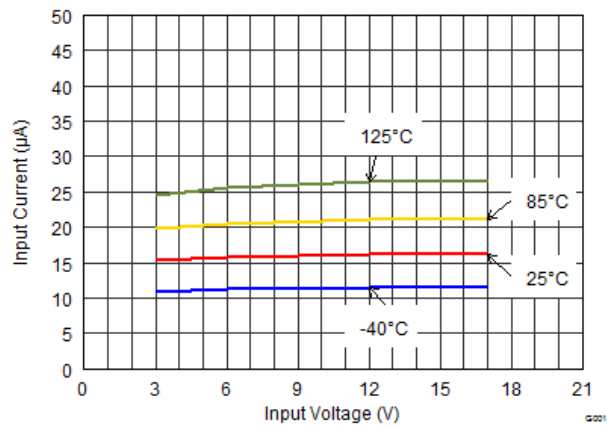
(3) This is the static current limit. It can be temporarily higher in applications due to internal propagation delay (see [Current Limit and Short Circuit Protection](#) section).

(4) The accuracy in Power Save Mode can be improved by increasing the  $C_{OUT}$  value, reducing the output voltage ripple.

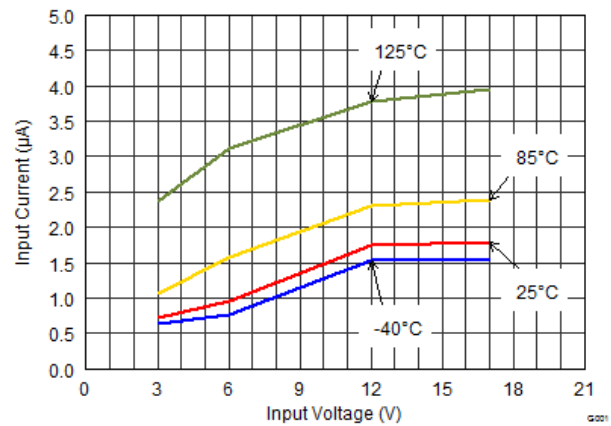
(5) Line and load regulation are depending on external component selection and layout (see [Figure 14](#) and [Figure 15](#)).

## 7.6 Typical Characteristics

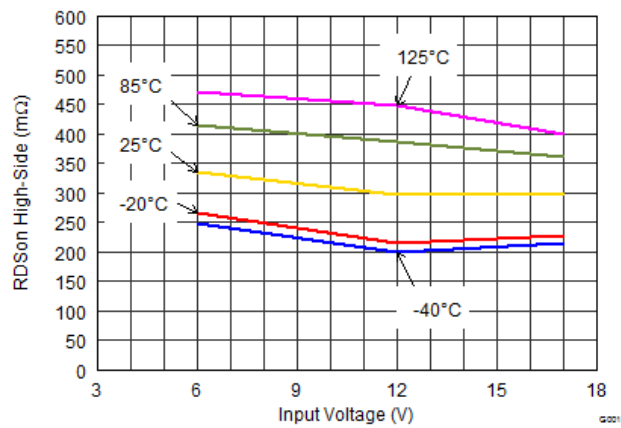
At  $V_{IN} = 12\text{ V}$ ,  $V_{OUT} = 3.3\text{ V}$  and  $T_J = 25^\circ\text{C}$  (unless otherwise noted)



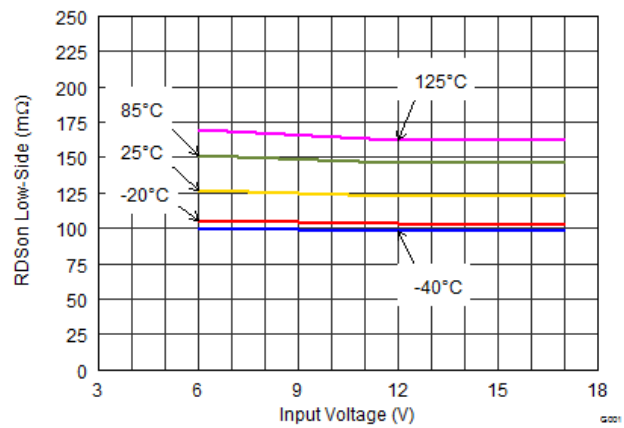
**Figure 1. Quiescent Current**



**Figure 2. Shutdown Current**



**Figure 3. High-Side Static Drain-Source-Resistance ( $R_{DS(on)}$ )**



**Figure 4. Low-Side Static Drain-Source-Resistance ( $R_{DS(on)}$ )**



## 8.3 Feature Description

### 8.3.1 Enable / Shutdown (EN)

When Enable (EN) is set High, the device starts operation.

Shutdown is forced if EN is pulled Low with a shutdown current of typically 1.5  $\mu$ A. During shutdown, the internal power MOSFETs as well as the entire control circuitry are turned off. The internal resistive divider pulls down the output voltage smoothly. If the EN pin is Low, an internal pull-down resistor of about 400 k $\Omega$  is connected and keeps it Low in case of floating pin.

Connecting the EN pin to an appropriate output signal of another power rail provides sequencing of multiple power rails.

### 8.3.2 Softstart

The internal soft start circuitry controls the output voltage slope during startup. This avoids excessive inrush current and ensures a controlled output voltage rise time. It also prevents unwanted voltage drops from high-impedance power sources or batteries. When EN is set to start device operation, the device starts switching after a delay of about 50  $\mu$ s and  $V_{OUT}$  rises with a slope of about 25 mV/ $\mu$ s. See [Figure 26](#) and [Figure 27](#) for typical startup operation.

The TPS62160-Q1 can start into a pre-biased output. During monotonic pre-biased startup, the low-side MOSFET is not allowed to turn on until the device's internal ramp sets an output voltage above the pre-bias voltage.

### 8.3.3 Power Good (PG)

The TPS62160-Q1 has a built in power good (PG) function to indicate whether the output voltage has reached its appropriate level or not. The PG signal can be used for startup sequencing of multiple rails. The PG pin is an open-drain output that requires a pull-up resistor (to any voltage below 7 V). It can sink 2 mA of current and maintain its specified logic low level. It is high impedance when the device is turned off due to EN, UVLO or thermal shutdown.

### 8.3.4 Under Voltage Lockout (UVLO)

If the input voltage drops, the under voltage lockout prevents misoperation of the device by switching off both the power FETs. The under voltage lockout threshold is set typically to 2.7 V. The device is fully operational for voltages above the UVLO threshold and turns off if the input voltage trips the threshold. The converter starts operation again once the input voltage exceeds the threshold by a hysteresis of typically 180 mV.

### 8.3.5 Thermal Shutdown

The junction temperature ( $T_J$ ) of the device is monitored by an internal temperature sensor. If  $T_J$  exceeds 160°C (typ), the device goes into thermal shut down. Both the high-side and low-side power FETs are turned off and PG goes high impedance. When  $T_J$  decreases below the hysteresis amount, the converter resumes normal operation, beginning with Soft Start. To avoid unstable conditions, a hysteresis of typically 20°C is implemented on the thermal shut down temperature.

## 8.4 Device Functional Modes

### 8.4.1 Pulse Width Modulation (PWM) Operation

The TPS62160-Q1 operates with pulse width modulation in continuous conduction mode (CCM) with a nominal switching frequency of about 2.25 MHz. The frequency variation in PWM is controlled and depends on  $V_{IN}$ ,  $V_{OUT}$  and the inductance. The device operates in PWM mode as long the output current is higher than half the inductor's ripple current. To maintain high efficiency at light loads, the device enters Power Save Mode at the boundary to discontinuous conduction mode (DCM). This happens if the output current becomes smaller than half the inductor's ripple current.



## Device Functional Modes (continued)

### 8.4.2 Power Save Operation

The TPS62160-Q1's built in Power Save Mode will be entered seamlessly, if the load current decreases. This secures a high efficiency in light load operation. The device remains in Power Save Mode as long as the inductor current is discontinuous.

In Power Save Mode the switching frequency decreases linearly with the load current maintaining high efficiency. The transition into and out of Power Save Mode happens within the entire regulation scheme and is seamless in both directions.

The TPS62160-Q1 includes a fixed on-time circuitry. This on-time, in steady-state operation, can be estimated as:

$$t_{ON} = \frac{V_{OUT}}{V_{IN}} \times 420\text{ns} \quad (1)$$

For very small output voltages, the on-time increases beyond the result of Equation 1, to stay above an absolute minimum on-time,  $t_{ON(min)}$ , which is around 80 ns to limit switching losses. The peak inductor current in PSM can be approximated by:

$$I_{LPSM(peak)} = \frac{(V_{IN} - V_{OUT})}{L} \times t_{ON} \quad (2)$$

When  $V_{IN}$  decreases to typically 15% above  $V_{OUT}$ , the TPS62160-Q1 does not enter Power Save Mode, regardless of the load current. The device maintains output regulation in PWM mode.

### 8.4.3 100% Duty-Cycle Operation

The duty cycle of the buck converter is given by  $D = V_{out}/V_{in}$  and increases as the input voltage comes close to the output voltage. In this case, the device starts 100% duty cycle operation turning on the high-side switch 100% of the time. The high-side switch stays turned on as long as the output voltage is below the internal set point. This allows the conversion of small input to output voltage differences, e.g. for longest operation time of battery-powered applications. In 100% duty cycle mode, the low-side FET is switched off.

The minimum input voltage to maintain output voltage regulation, depending on the load current and the output voltage level, can be calculated as:

$$V_{IN(min)} = V_{OUT(min)} + I_{OUT} (R_{DS(on)} + R_L) \quad (3)$$

where

$I_{OUT}$  is the output current,

$R_{DS(on)}$  is the  $R_{DS(on)}$  of the high-side FET and

$R_L$  is the DC resistance of the inductor used.

### 8.4.4 Current Limit and Short Circuit Protection

The TPS62160-Q1 is protected against heavy load and short circuit events. At heavy loads, the current limit determines the maximum output current. If the current limit is reached, the high-side FET will be turned off. Avoiding shoot through current, the low-side FET will be switched on to sink the inductor current. The high-side FET will turn on again, only if the current in the low-side FET has decreased below the low side current limit threshold.

## Device Functional Modes (continued)

The output current of the device is limited by the current limit (see [Electrical Characteristics](#)). Due to internal propagation delay, the actual current can exceed the static current limit during that time. The dynamic current limit can be calculated as follows:

$$I_{\text{peak(typ)}} = I_{\text{LIMF}} + \frac{V_L}{L} \times t_{\text{PD}} \quad (4)$$

where

$I_{\text{LIMF}}$  is the static current limit, specified in the electrical characteristic table,

$L$  is the inductor value,

$V_L$  is the voltage across the inductor and

$t_{\text{PD}}$  is the internal propagation delay.

The dynamic high side switch peak current can be calculated as follows:

$$I_{\text{peak(typ)}} = I_{\text{LIMF\_HS}} + \frac{(V_{\text{IN}} - V_{\text{OUT}})}{L} \times 30\text{ns} \quad (5)$$

Care on the current limit has to be taken if the input voltage is high and very small inductances are used.

### 8.4.5 Operation Above $T_J = 125^\circ\text{C}$

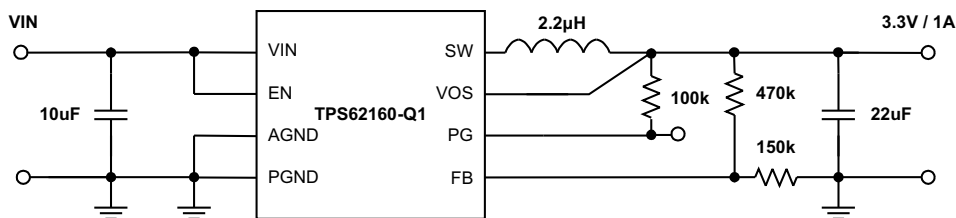
The operating junction temperature of the device is specified up to  $125^\circ\text{C}$ . In power supply circuits, the self heating effect causes, that the junction temperature,  $T_J$ , is even higher than the ambient temperature  $T_A$ . Depending on  $T_A$  and the load current, the maximum operating temperature  $T_J$  can be exceeded. However, the electrical characteristics are specified up to a  $T_J$  of  $125^\circ\text{C}$  only. The device operates as long as thermal shutdown threshold is not triggered.

## 9 Application and Implementation

### 9.1 Application Information

The TPS62160-Q1 is a synchronous switched mode step-down converter, able to convert a 3 V to 17 V input voltage into a lower, 0.9 V to 6 V, output voltage, providing up to 1-A load current. The following section gives guidance on the external component selection to operate the device within the recommended operating conditions.

### 9.2 Typical TPS62160-Q1 Application



**Figure 5. 3.3-V / 1-A Power Supply**

#### 9.2.1 Design Requirements

The step-down converter design can be adapted to different output voltage and load current needs by choosing external components appropriate. The following design procedure is adequate for whole VIN, VOUT, and load current range of TPS62160-Q1. Using [Table 2](#), the design procedure needs minimum effort.

**Table 1. Components Used for Application Characteristics**

REFERENCE	DESCRIPTION	MANUFACTURER
IC	17-V, 1-A step-down converter, WSON	TPS62160QDSG, Texas Instruments
L1	2.2-µH, 1.4-A, 3 x 2.8 x 1.2 mm	VLF3012ST-2R2M1R4, TDK
CIN	10-µF, 25-V, ceramic	Standard
COUT	22-µF, 6.3-V, ceramic	Standard
R1	Depending on Vout	
R2	Depending on Vout	
R3	100-kΩ, chip, 0603, 1/16-W, 1%	Standard

#### 9.2.2 Detailed Design Procedure

##### 9.2.2.1 Programming the Output Voltage

The TPS62160-Q1 can be programmed for output voltages from 0.9 V to 6 V by using a resistive divider from VOUT to FB to AGND. The voltage at the FB pin is regulated to 800 mV. The value of the output voltage is set by the selection of the resistive divider from [Equation 6](#). It is recommended to choose resistor values which allow a cross current of at least 2 µA, meaning the value of R2 should not exceed 400 kΩ. Lower resistor values are recommended for highest accuracy and most robust design. For applications requiring lowest current consumption, the use of fixed output voltage versions is recommended.

$$R_1 = R_2 \left( \frac{V_{OUT}}{V_{REF}} - 1 \right) \quad (6)$$

In case the FB pin gets opened, the device clamps the output voltage at the VOS pin to about 7.4 V.

### 9.2.2.2 External Component Selection

The external components have to fulfill the needs of the application, but also the stability criteria of the devices control loop. The TPS62160-Q1 is optimized to work within a range of external components. The LC output filters inductance and capacitance have to be considered together, creating a double pole, responsible for the corner frequency of the converter (see [Output Filter And Loop Stability](#) section). [Table 2](#) can be used to simplify the output filter component selection.

**Table 2. Recommended LC Output Filter Combinations<sup>(1)</sup>**

	4.7μF	10μF	22μF	47μF	100μF	200μF	400μF
1μH							
2.2μH		√	√ <sup>(2)</sup>	√	√	√	
3.3μH		√	√	√	√		
4.7μH							

(1) The values in the table are nominal values. Variations of typically ±20% due to tolerance, saturation and DC bias are assumed.

(2) This LC combination is the standard value and recommended for most applications.

More detailed information on further LC combinations can be found in [SLVA463](#).

#### 9.2.2.2.1 Inductor Selection

The inductor selection is affected by several effects like inductor ripple current, output ripple voltage, PWM-to-PSM transition point and efficiency. In addition, the inductor selected has to be rated for appropriate saturation current and DC resistance (DCR). [Equation 7](#) and [Equation 8](#) calculate the maximum inductor current under static load conditions.

$$I_{L(max)} = I_{OUT(max)} + \frac{\Delta I_{L(max)}}{2} \quad (7)$$

$$\Delta I_{L(max)} = V_{OUT} \times \left( \frac{1 - \frac{V_{OUT}}{V_{IN(max)}}}{L(min) \times f_{SW}} \right) \quad (8)$$

where

$I_L(max)$  is the maximum inductor current,  
 $\Delta I_L$  is the Peak-to-Peak Inductor Ripple Current,  
 $L(min)$  is the minimum effective inductor value and  
 $f_{SW}$  is the actual PWM Switching Frequency.

Calculating the maximum inductor current using the actual operating conditions gives the minimum saturation current of the inductor needed. A margin of about 20% is recommended to add. A larger inductor value is also useful to get lower ripple current, but increases the transient response time and size as well. The following inductors have been used with the TPS62160-Q1 and are recommended for use:

**Table 3. List of Inductors**

TYPE	INDUCTANCE [ $\mu$ H]	CURRENT [A] <sup>(1)</sup>	DIMENSIONS [L x B x H] mm	MANUFACTURER
VLF3012ST-2R2M1R4	2.2 $\mu$ H, $\pm$ 20%	1.9 A	3.0 x 2.8 x 1.2	TDK
VLF302512MT-2R2M	2.2 $\mu$ H, $\pm$ 20%	1.9 A	3.0 x 2.5 x 1.2	TDK
VLS252012T-2R2M1R3	2.2 $\mu$ H, $\pm$ 20%	1.3 A	2.5 x 2.0 x 1.2	TDK
XFL3012-222MEC	2.2 $\mu$ H, $\pm$ 20%	1.9 A	3.0 x 3.0 x 1.2	Coilcraft
XFL3012-332MEC	3.3 $\mu$ H, $\pm$ 20%	1.6 A	3.0 x 3.0 x 1.2	Coilcraft
LPS3015-332ML_	3.3 $\mu$ H, $\pm$ 20%	1.4 A	3.0 x 3.0 x 1.4	Coilcraft
NR3015T-2R2M	2.2 $\mu$ H, $\pm$ 20%	1.5 A	3.0 x 3.0 x 1.5	Taiyo Yuden
744025003	3.3 $\mu$ H, $\pm$ 20%	1.5 A	2.8 x 2.8 x 2.8	Wuerth
PSI25201B-2R2MS	2.2 $\mu$ H, $\pm$ 20%	1.3 A	2.0 x 2.5 x 1.2	Cyntec

(1)  $I_{RMS}$  at 40°C rise or  $I_{SAT}$  at 30% drop.

The TPS62160-Q1 can be run with an inductor as low as 2.2  $\mu$ H. However, for applications with low input voltages, 3.3  $\mu$ H is recommended, to allow the full output current. The inductor value also determines the load current at which Power Save Mode is entered:

$$I_{load(PSM)} = \frac{1}{2} \Delta I_L \quad (9)$$

Using [Equation 8](#), this current level can be adjusted by changing the inductor value.

#### 9.2.2.2.2 Capacitor Selection

##### 9.2.2.2.2.1 Output Capacitor

The recommended value for the output capacitor is 22  $\mu$ F. The architecture of the TPS62160-Q1 allows the use of tiny ceramic output capacitors with low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are recommended. To keep its low resistance up to high frequencies and to get narrow capacitance variation with temperature, it's recommended to use X7R or X5R dielectric. Using a higher value can have some advantages like smaller voltage ripple and a tighter DC output accuracy in Power Save Mode (see [SLVA463](#)).

#### NOTE

In power save mode, the output voltage ripple depends on the output capacitance, its ESR and the peak inductor current. Using ceramic capacitors provides small ESR and low ripple.

##### 9.2.2.2.2.2 Input Capacitor

For most applications, 10  $\mu$ F is sufficient and is recommended, though a larger value reduces input current ripple further. The input capacitor buffers the input voltage for transient events and also decouples the converter from the supply. A low ESR multilayer ceramic capacitor is recommended for best filtering and should be placed between VIN and GND as close as possible to those pins.

#### NOTE

**DC Bias effect:** High capacitance ceramic capacitors have a DC Bias effect, which will have a strong influence on the final effective capacitance. Therefore the right capacitor value has to be chosen carefully. Package size and voltage rating in combination with dielectric material are responsible for differences between the rated capacitor value and the effective capacitance.

### 9.2.2.3 Output Filter And Loop Stability

The TPS62160-Q1 is internally compensated to be stable with L-C filter combinations corresponding to a corner frequency to be calculated with [Equation 10](#):

$$f_{LC} = \frac{1}{2\pi\sqrt{L \times C}} \quad (10)$$

Proven nominal values for inductance and ceramic capacitance are given in [Table 2](#) and are recommended for use. Different values may work, but care has to be taken on the loop stability which might be affected. More information including a detailed L-C stability matrix can be found in [SLVA463](#).

The TPS62160-Q1 includes an internal 25-pF feedforward capacitor, connected between the VOS and FB pins. This capacitor impacts the frequency behavior and sets a pole and zero in the control loop with the resistors of the feedback divider, per [Equation 11](#) and [Equation 12](#):

$$f_{zero} = \frac{1}{2\pi \times R_1 \times 25 \text{ pF}} \quad (11)$$

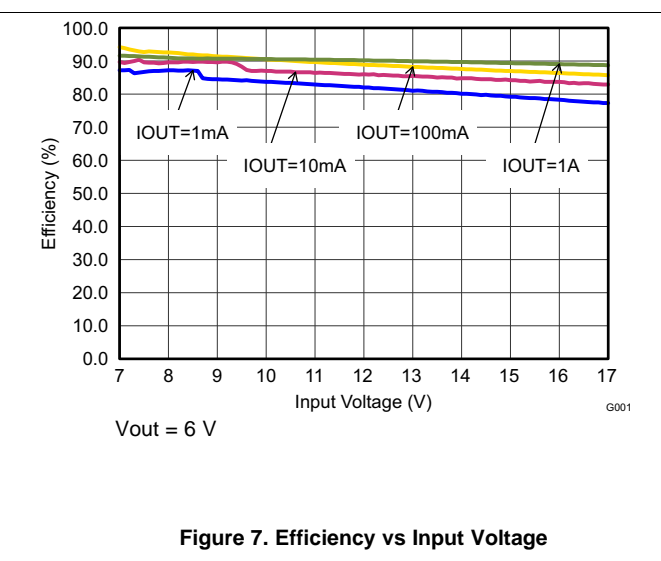
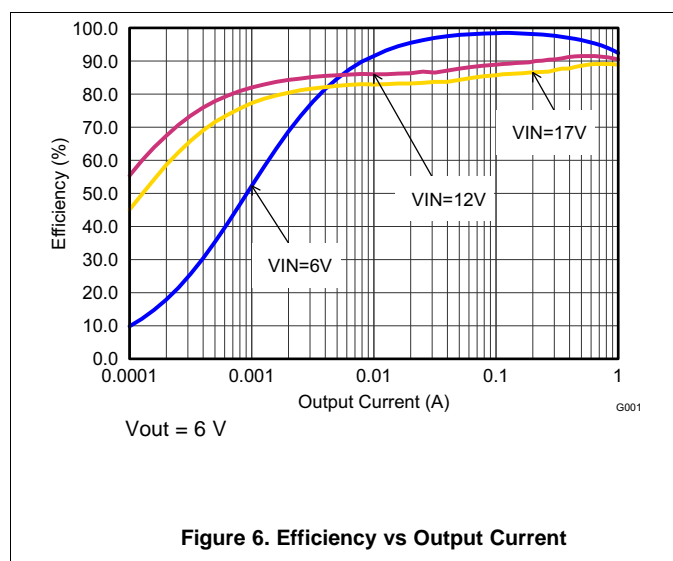
$$f_{pole} = \frac{1}{2\pi \times 25 \text{ pF}} \times \left( \frac{1}{R_1} + \frac{1}{R_2} \right) \quad (12)$$

Though the TPS62160-Q1 is stable without the pole and zero being in a particular location, adjusting their location to the specific needs of the application can provide better performance in Power Save mode and/or improved transient response. An external feedforward capacitor can also be added. A more detailed discussion on the optimization for stability vs transient response can be found in [SLVA289](#) and [SLVA466](#).

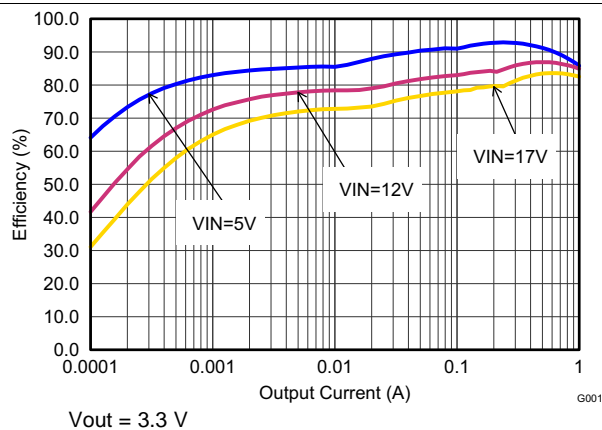
If using ceramic capacitors, the DC bias effect has to be considered. The DC bias effect results in a drop in effective capacitance as the voltage across the capacitor increases (see **NOTE** in [DC Bias effect](#) section).

### 9.2.3 Application Performance Plots

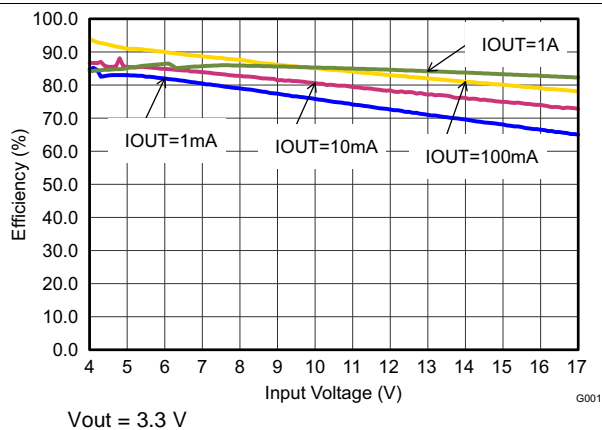
At  $V_{IN} = 12 \text{ V}$ ,  $V_{OUT} = 3.3 \text{ V}$  and  $T_J = 25^\circ\text{C}$  (unless otherwise noted)



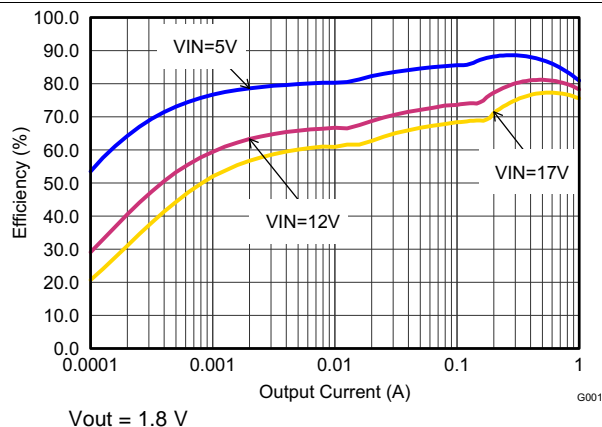
At  $V_{IN} = 12\text{ V}$ ,  $V_{OUT} = 3.3\text{ V}$  and  $T_J = 25^\circ\text{C}$  (unless otherwise noted)



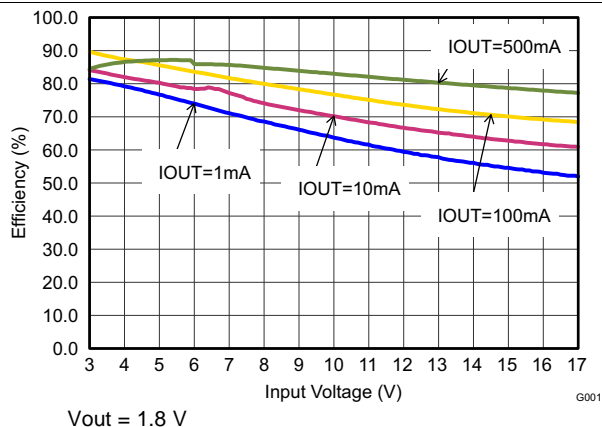
**Figure 8. Efficiency vs Output Current**



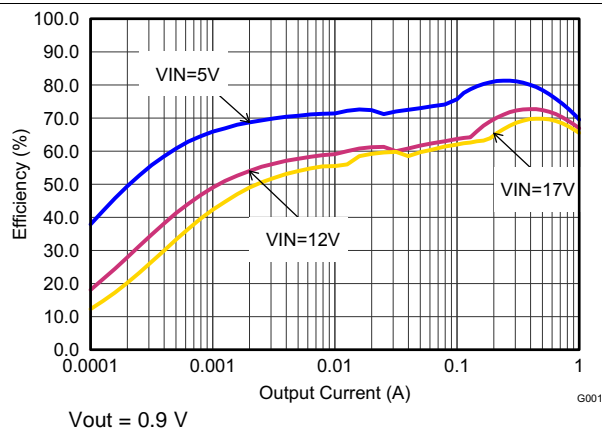
**Figure 9. Efficiency vs Input Voltage**



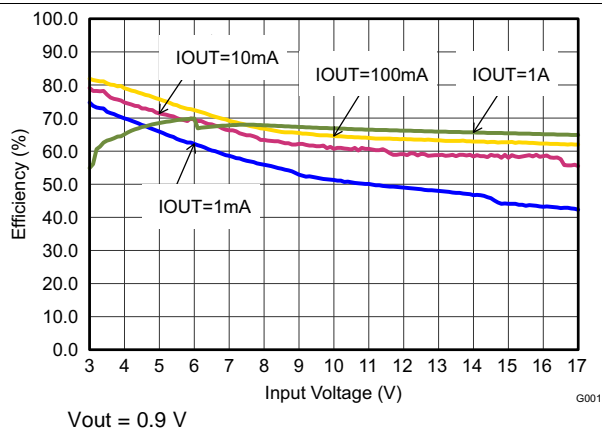
**Figure 10. Efficiency vs Output Current**



**Figure 11. Efficiency vs Input Voltage**



**Figure 12. Efficiency vs Output Current**



**Figure 13. Efficiency vs Input Voltage**

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At  $V_{IN} = 12\text{ V}$ ,  $V_{OUT} = 3.3\text{ V}$  and  $T_J = 25^\circ\text{C}$  (unless otherwise noted)

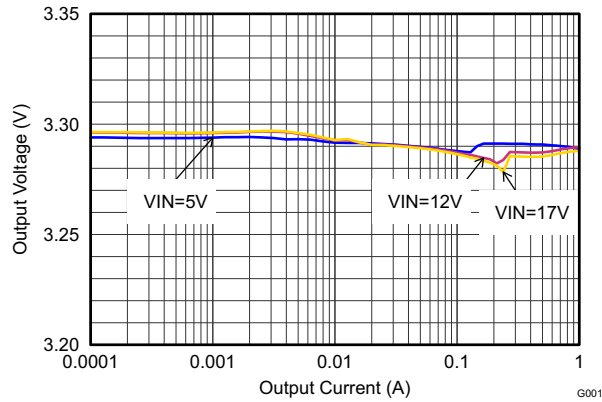


Figure 14. Output Voltage Accuracy (Load Regulation)

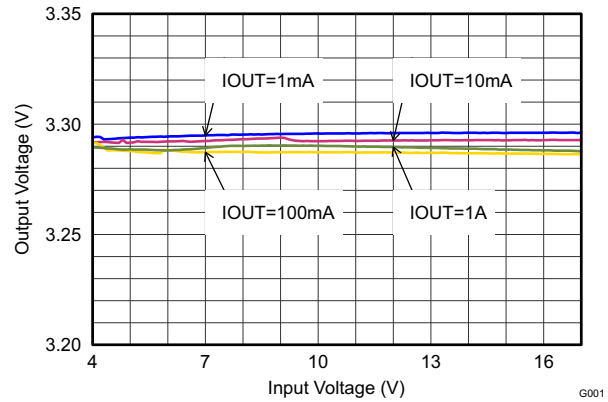


Figure 15. Output Voltage Accuracy (Line Regulation)

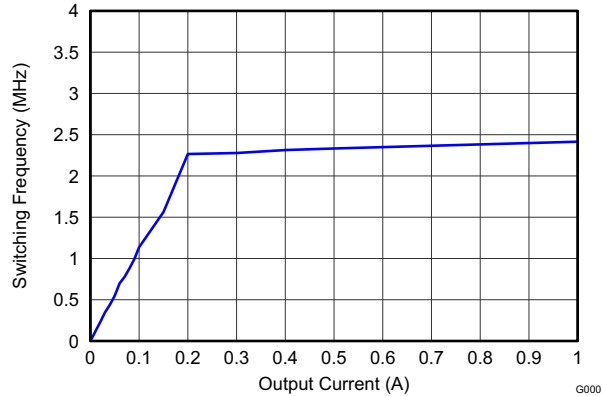


Figure 16. Switching Frequency vs Output Current

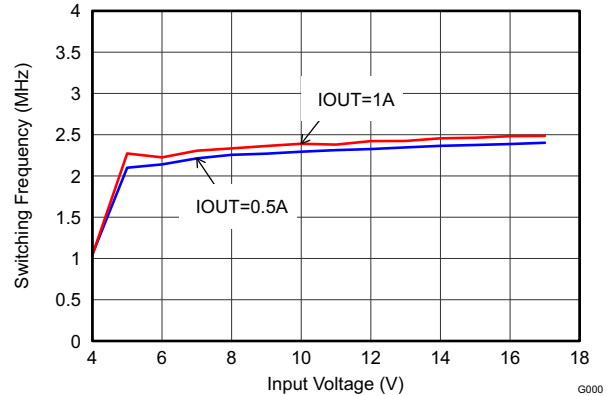


Figure 17. Switching Frequency vs Input Voltage

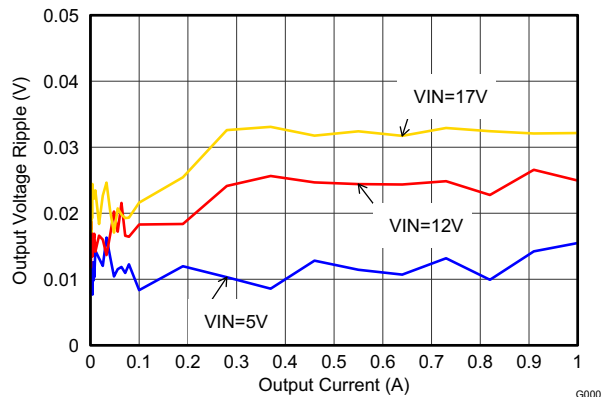


Figure 18. Output Voltage Ripple

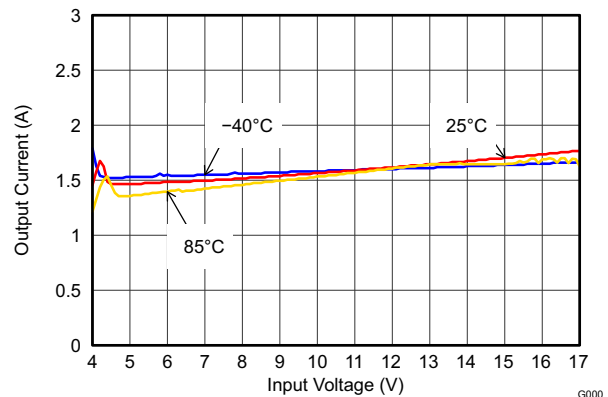
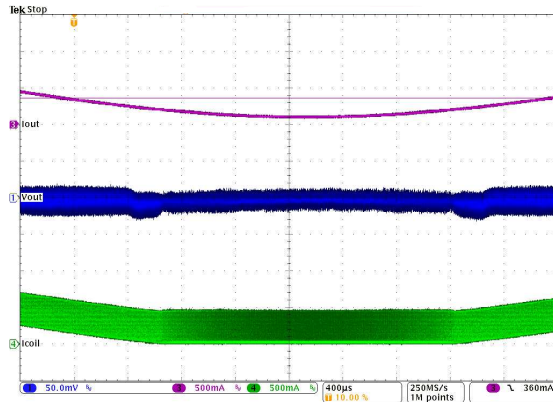


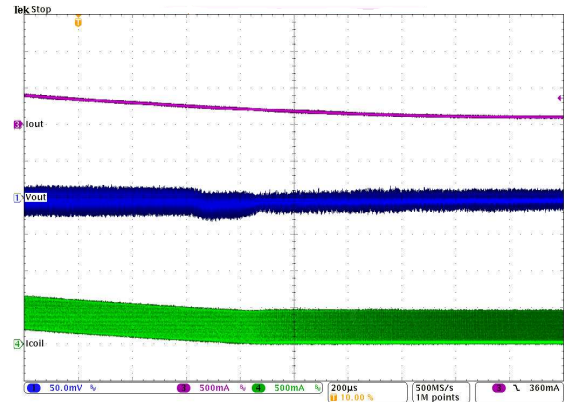
Figure 19. Maximum Output Current



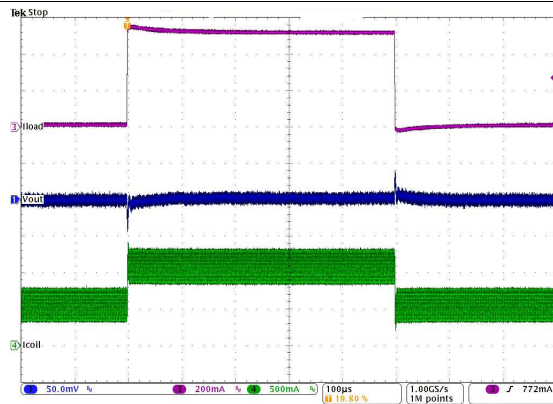
At  $V_{IN} = 12\text{ V}$ ,  $V_{OUT} = 3.3\text{ V}$  and  $T_J = 25^\circ\text{C}$  (unless otherwise noted)



**Figure 20. PWM / PSM Mode Transitions**

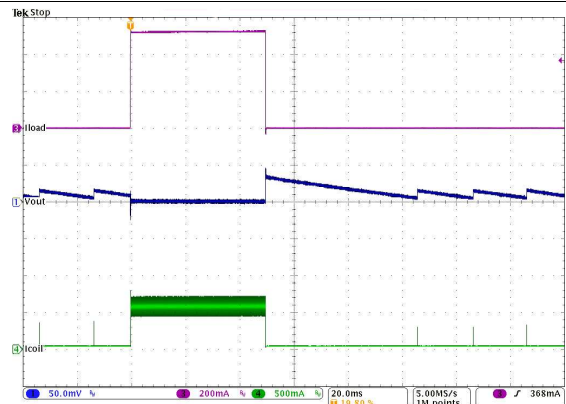


**Figure 21. PWM to PSM Mode Transition**



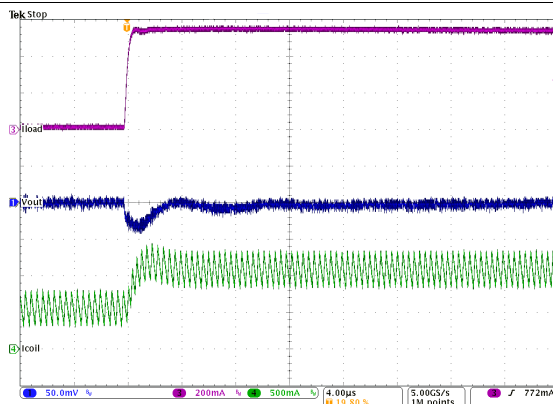
500 mA to 1 A

**Figure 22. Load Transient Response in PWM Mode**



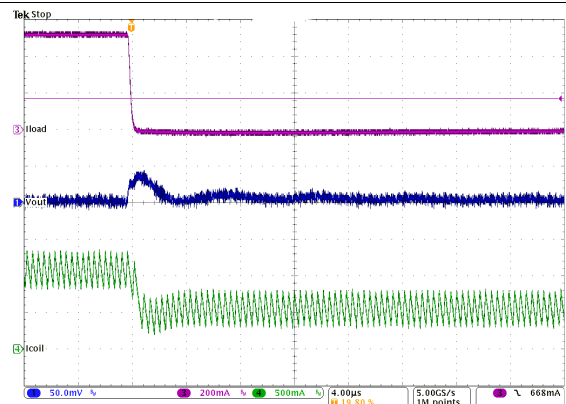
100 mA to 500 mA

**Figure 23. Load Transient Response from Power Save Mode**



500 mA to 1 A, Rising edge

**Figure 24. Load Transient Response in PWM Mode**



500 mA to 1 A, Falling edge

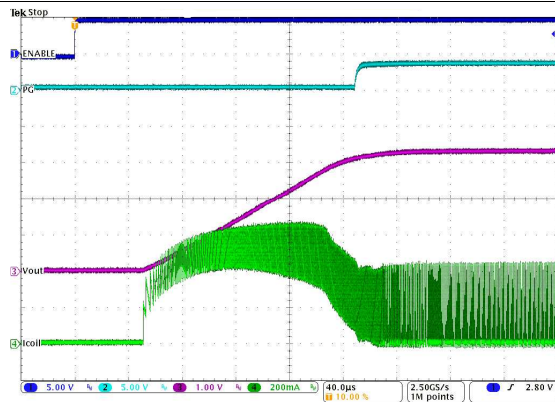
**Figure 25. Load Transient Response in PWM Mode**

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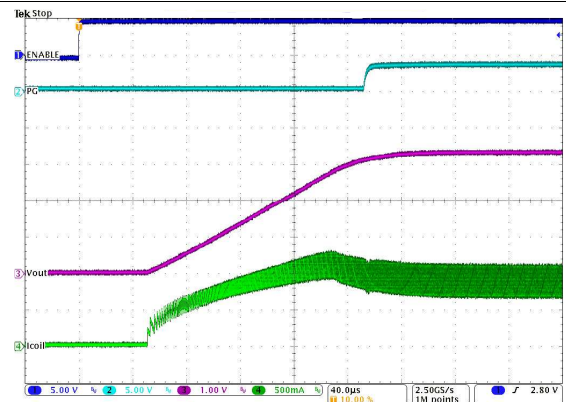
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At  $V_{IN} = 12\text{ V}$ ,  $V_{OUT} = 3.3\text{ V}$  and  $T_J = 25^\circ\text{C}$  (unless otherwise noted)



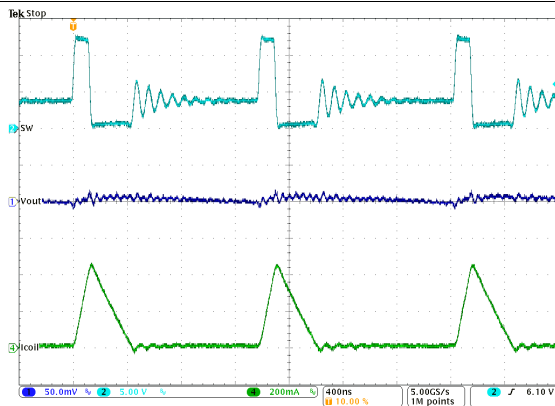
$I_{out} = 100\text{ mA}$

**Figure 26. Startup**



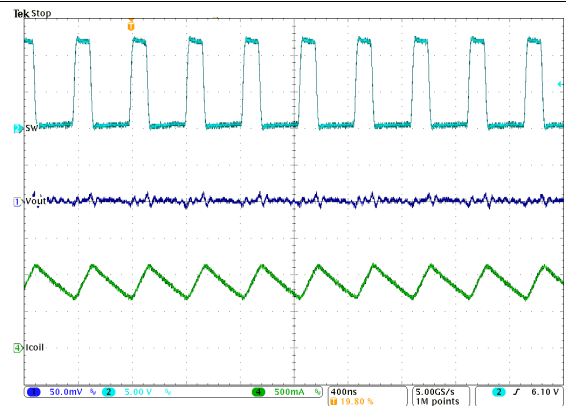
$I_{out} = 1\text{ A}$

**Figure 27. Startup**



$I_{out} = 66\text{ mA}$

**Figure 28. Typical Operation in Power Save Mode**



$I_{out} = 1\text{ A}$

**Figure 29. Typical Operation in PWM Mode**

## 9.3 System Examples

### 9.3.1 Inverting Power Supply

The TPS62160-Q1 can be used as inverting power supply by rearranging external circuitry as shown in [Figure 30](#). As the former GND node now represents a voltage level below system ground, the voltage difference between  $V_{IN}$  and  $V_{OUT}$  has to be limited for operation to the maximum supply voltage of 17 V (see [Equation 13](#)).

$$V_{IN} + V_{OUT} \leq V_{IN\ max} \quad (13)$$

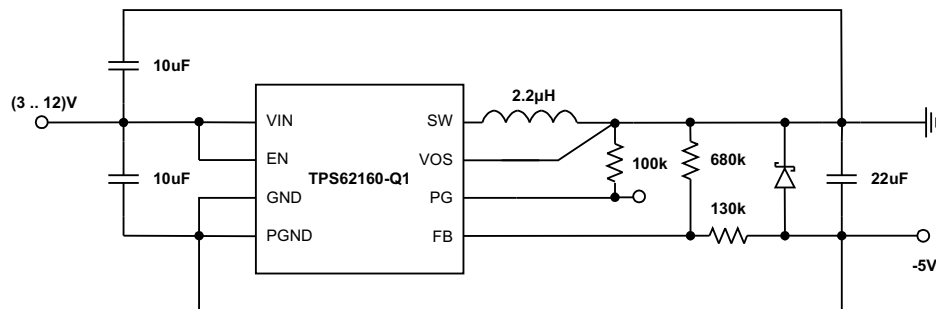


Figure 30. -5-V Inverting Power Supply

The transfer function of the inverting power supply configuration differs from the buck mode transfer function, incorporating a Right Half Plane Zero additionally. The loop stability has to be adapted and an output capacitance of at least 22  $\mu$ F is recommended. A detailed design example is given in [SLVA469](#).

### 9.3.2 Various Output Voltages

The TPS62160-Q1 can be set for different output voltages between 0.9 V and 6 V. Some examples are shown below.

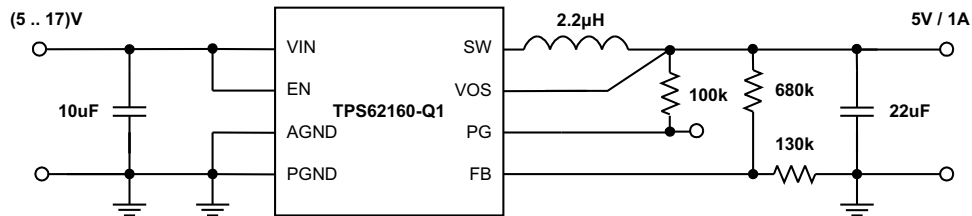
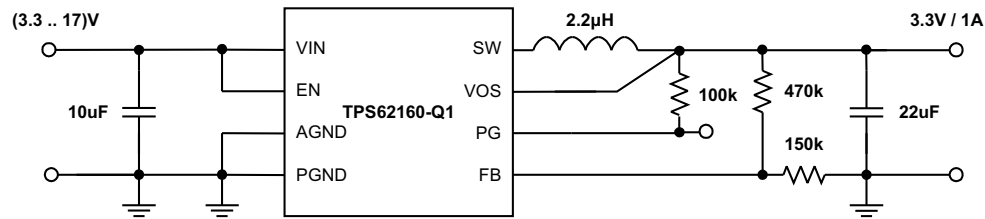
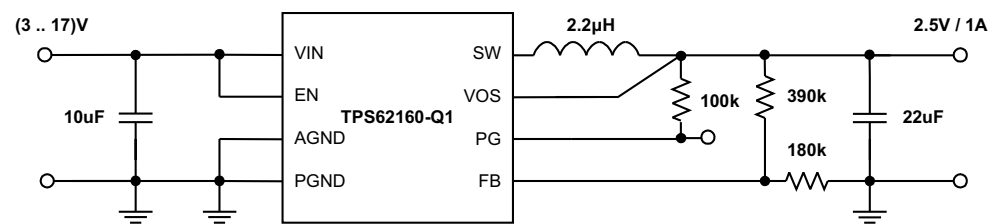


Figure 31. 5-V/1-A Power Supply

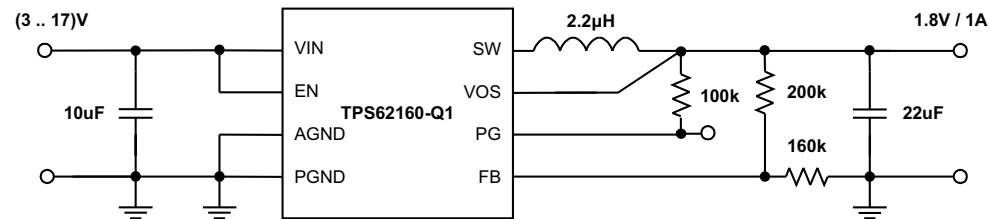
## System Examples (continued)



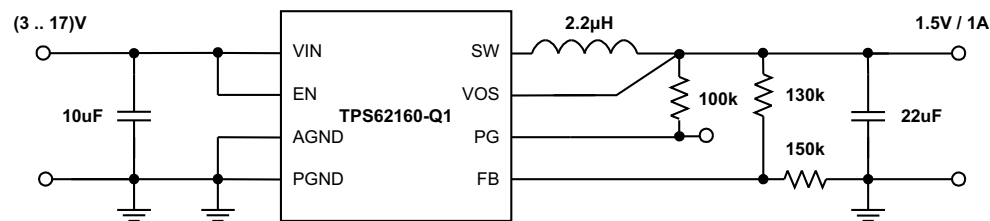
**Figure 32. 3.3-V/1-A Power Supply**



**Figure 33. 2.5-V/1-A Power Supply**

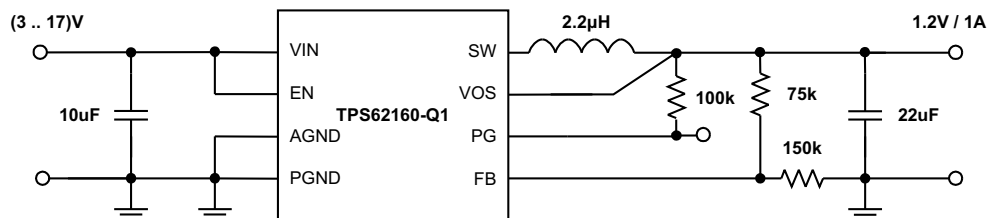


**Figure 34. 1.8-V/1-A Power Supply**

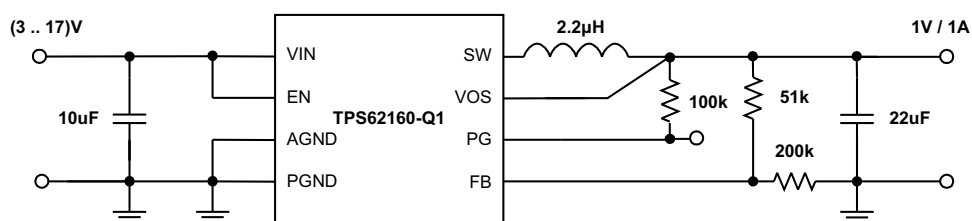


**Figure 35. 1.5-V/1-A Power Supply**

## System Examples (continued)



**Figure 36. 1.2-V/1-A Power Supply**



**Figure 37. 1-V/1-A Power Supply**

## 10 Power Supply Recommendations

The TPS62160-Q1 is designed to operate from a 3-V to 17-V input voltage supply. The input power supply's output current needs to be rated according to the output voltage and the output current of the power rail application.

## 11 Layout

### 11.1 Layout Guidelines

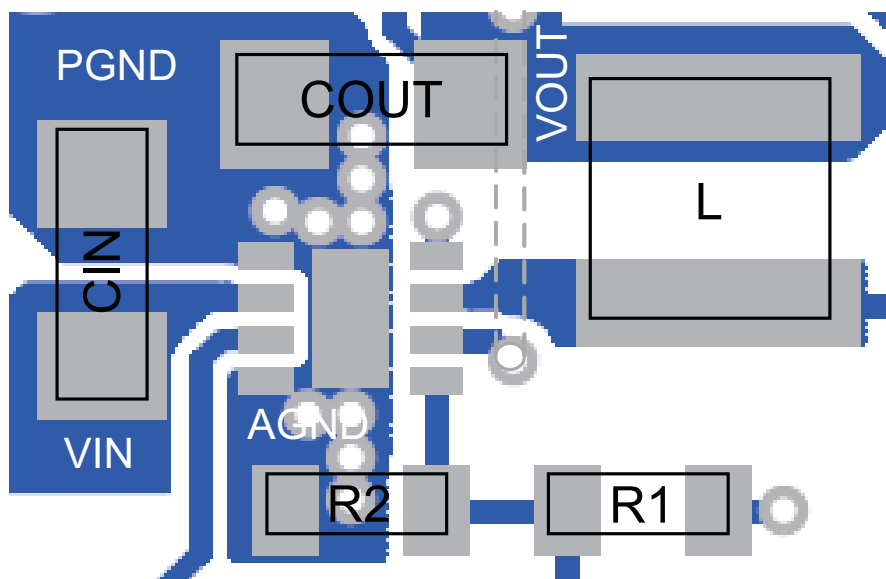
A proper layout is critical for the operation of a switched mode power supply, even more at high switching frequencies. Therefore the PCB layout of the TPS62160-Q1 demands careful attention to ensure operation and to get the performance specified. A poor layout can lead to issues like poor regulation (both line and load), stability and accuracy weaknesses, increased EMI radiation and noise sensitivity. Considering the following topics ensures best electrical and optimized thermal performance:

- 1) The input capacitor must be placed as close as possible to the VIN and PGND pin of the IC. This provides low resistive and inductive path for the high di/dt input current.
- 2) The VOS pin must be connect in the shortest way to VOUT at the output capacitor - avoiding noise coupling.
- 3) The feedback resistors, R1 and R2 must be connected close to the FB and AGND pins - avoiding noise coupling.
- 4) The output capacitor should be placed such that its ground is as close as possible to the IC's PGND pins - avoiding additional voltage drop in traces.
- 5) The inductor should be placed close to the SW pin and connect directly to the output capacitor - minimizing the loop area between the SW pin, inductor, output capacitor and PGND pin.

More detailed information can be found in the *EVM Users Guide*, [SLVU483](#).

The Exposed Thermal Pad must be soldered to the circuit board for mechanical reliability and to achieve appropriate power dissipation. Although the Exposed Thermal Pad can be connected to a floating circuit board trace, the device will have better thermal performance if it is connected to a larger ground plane. The Exposed Thermal Pad is electrically connected to AGND.

### 11.2 Layout Example



**Figure 38. Layout Example**

### 11.3 Thermal Considerations

Implementation of integrated circuits in low-profile and fine-pitch surface-mount packages typically requires special attention to power dissipation. Many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components affect the power-dissipation limits of a given component.

Three basic approaches for enhancing thermal performance are listed below:

- Improving the power dissipation capability of the PCB design
- Improving the thermal coupling of the component to the PCB by soldering the Exposed Thermal Pad
- Introducing airflow in the system

For more details on how to use the thermal parameters, see the application notes: *Thermal Characteristics Application Note* ([SZZA017](#)), and ([SPRA953](#)).

The TPS62160-Q1 is designed for a maximum operating junction temperature ( $T_J$ ) of 125°C. Therefore the maximum output power is limited by the power losses that can be dissipated over the actual thermal resistance, given by the package and the surrounding PCB structures. Since the thermal resistance of the package is fixed, increasing the size of the surrounding copper area and improving the thermal connection to the IC can reduce the thermal resistance. To get an improved thermal behavior, it's recommended to use top layer metal to connect the device with wide and thick metal lines. Internal ground layers can connect to vias directly under the IC for improved thermal performance.

If short circuit or overload conditions are present, the device is protected by limiting internal power dissipation.

## 12 器件和文档支持

### 12.1 器件支持

#### 12.1.1 第三方产品免责声明

TI 发布的与第三方产品或服务有关的信息，不能构成与此类产品或服务或保修的适用性有关的认可，不能构成此类产品或服务单独或与任何 TI 产品或服务一起的表示或认可。

### 12.2 文档支持

#### 12.2.1 相关文档

应用报告《优化 TPS62130/40/50/60/70 输出滤波器》（文献编号：SLVA463）

应用报告《采用前馈电容优化内部补偿 DC-DC 转换器的瞬态响应》（文献编号：SLVA289）

应用报告《采用前馈电容优化 TPS62130/40/50/60/70 的稳定性和带宽》（文件编号：SLVA466）

用户指南《TPS62160EVM-627 和 TPS62170EVM-627 评估模块》（文献编号：SLVU483）

应用报告《采用 JEDEC PCB 设计的线性和逻辑封装散热特性》（文件编号：SZZA017）

应用报告《半导体和 IC 封装热指标》（文件编号：SPRA953）

### 12.3 商标

DCS-Control is a trademark of Texas Instruments.

### 12.4 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

### 12.5 术语表

[SLYZ022](#) — TI 术语表。

这份术语表列出并解释术语、首字母缩略词和定义。

## 13 机械封装和可订购信息

以下页中包括机械封装和可订购信息。 这些信息是针对指定器件可提供的最新数据。 这些数据会在无通知且不对本文档进行修订的情况下发生改变。 欲获得该数据表的浏览器版本，请查阅左侧的导航栏。



## PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">TPS62160QDSGRQ1</a>	Active	Production	WSO (DSG)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QTVQ
TPS62160QDSGRQ1.A	Active	Production	WSO (DSG)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QTVQ
TPS62160QDSGRQ1.B	Active	Production	WSO (DSG)   8	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QTVQ
<a href="#">TPS62160QDSGTQ1</a>	Active	Production	WSO (DSG)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QTVQ
TPS62160QDSGTQ1.A	Active	Production	WSO (DSG)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QTVQ
TPS62160QDSGTQ1.B	Active	Production	WSO (DSG)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	QTVQ

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TPS62160-Q1 :**

- Catalog : [TPS62160](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

## GENERIC PACKAGE VIEW

**DSG 8**

**WSON - 0.8 mm max height**

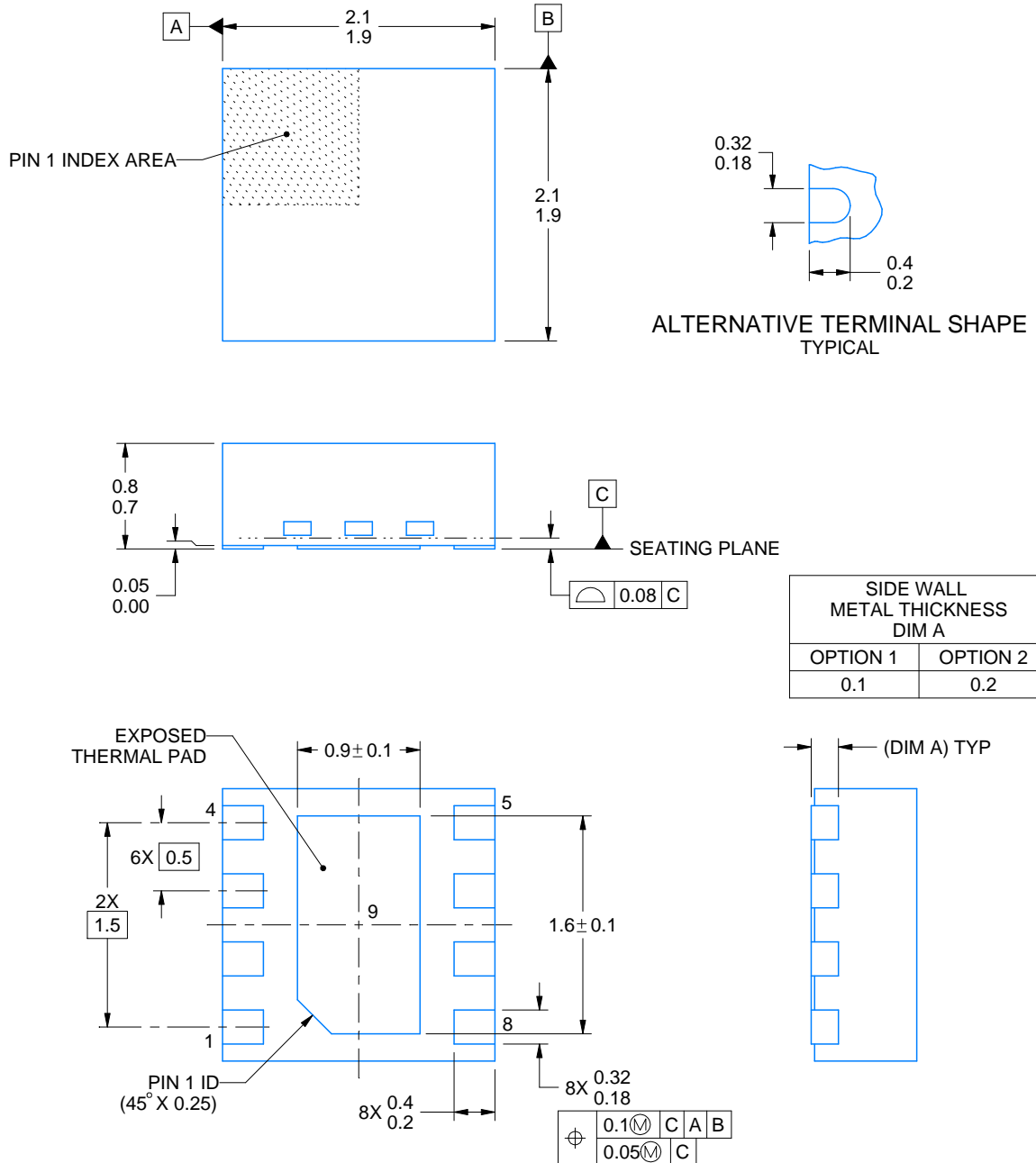
2 x 2, 0.5 mm pitch

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4224783/A



4218900/E 08/2022

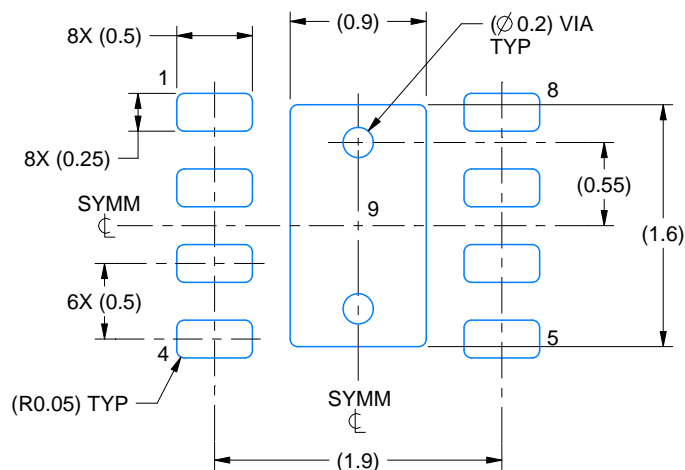
**NOTES:**

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

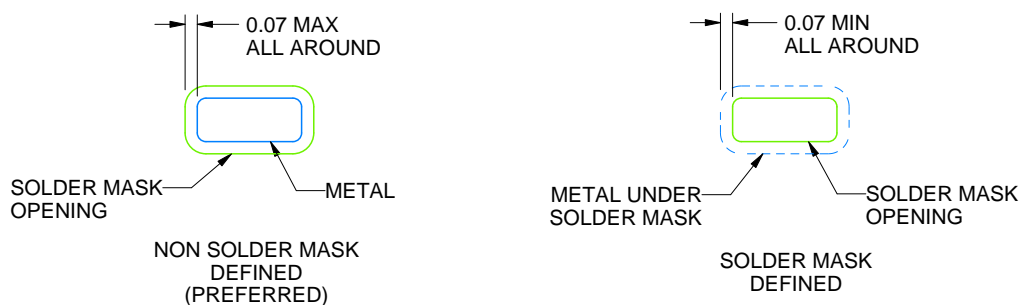
**DSG0008A**

**WSON - 0.8 mm max height**

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE  
SCALE:20X



## SOLDER MASK DETAILS

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NOTES: (continued)

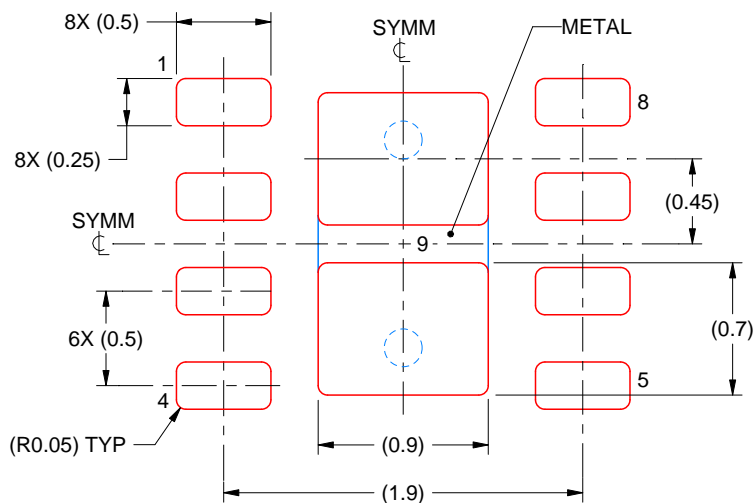
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slue271](http://www.ti.com/lit/slue271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

## EXAMPLE STENCIL DESIGN

DSG0008A

WSN - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 9:  
87% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
SCALE:25X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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